

< X/Ku band internally matched power GaAs FET >

# MGFK25V4045

14.0 – 14.5 GHz BAND / 0.3W

## DESCRIPTION

The MGFK25V4045 is an internally impedance-matched GaAs power FET especially designed for use in 14.0 – 14.5 GHz band amplifiers. The hermetically sealed metal-ceramic package guarantees high reliability.

## FEATURES

Internally matched to 50(ohm) system  
Flip-chip mounted

- High output power  
P1dB=0.3W (TYP.) @f=14.0 – 14.5GHz
- High linear power gain  
GLP=9.0dB (TYP.) @f=14.0 – 14.5GHz
- High power added efficiency  
P.A.E.=25% (TYP.) @f=14.0 – 14.5GHz

## APPLICATION

- 14.0 – 14.5 GHz band power amplifiers

## QUALITY GRADE

- IG

## RECOMMENDED BIAS CONDITIONS

- VDS=8V • ID=80mA Refer to Bias Procedure

## Absolute maximum ratings (Ta=25°C)

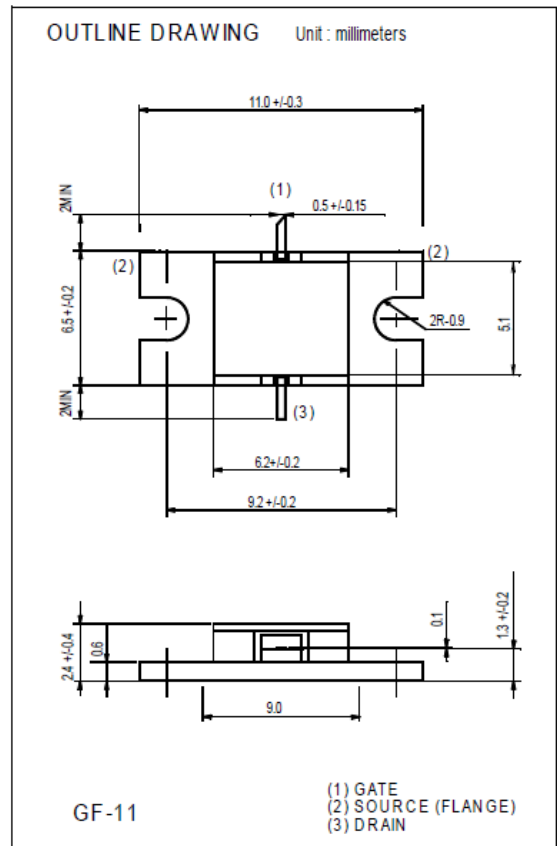
Symbol	Parameter	Ratings	Unit
VGDO	Gate to drain breakdown voltage	-15	V
VGSO	Gate to source breakdown voltage	-15	V
ID	Drain current	500	mA
IGR	Reverse gate current	-1	mA
IGF	Forward gate current	1	mA
PT *1	Total power dissipation	2.7	W
Tch	Channel temperature	175	°C
Tstg	Storage temperature	-65 to +175	°C

\*1 : Tc=25°C

## Electrical characteristics (Ta=25°C)

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
IDSS	Saturated drain current	VDS=3V, VGS=0V	-	200	500	mA
gm	Transconductance	VDS=3V, ID=150mA	-	100	-	mS
VGS(off)	Gate to source cut-off voltage	VDS=3V, ID=1mA	-2	-	-5	V
P1dB	Output power at 1dB gain compression	VDS=8V, ID(RF off)=150mA f=14.0 – 14.5GHz	23	26	-	dBm
GLP	Linear Power Gain		7	9	-	dB
PAE	Power added efficiency		-	25	-	%
Rth(ch-c) *2	Thermal resistance	delta Vf method	-	-	40	°C/W

\*2 : Channel-case



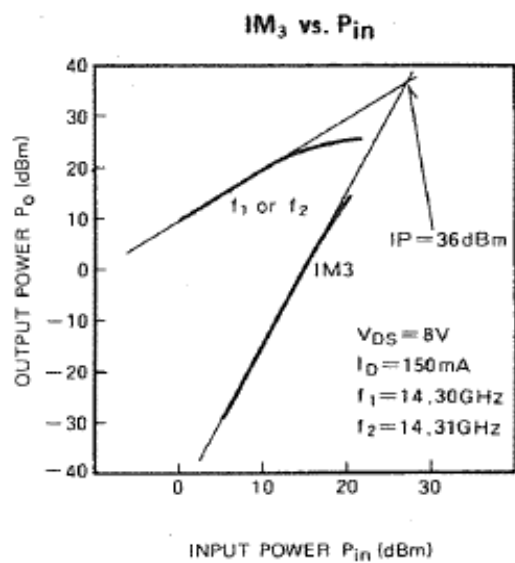
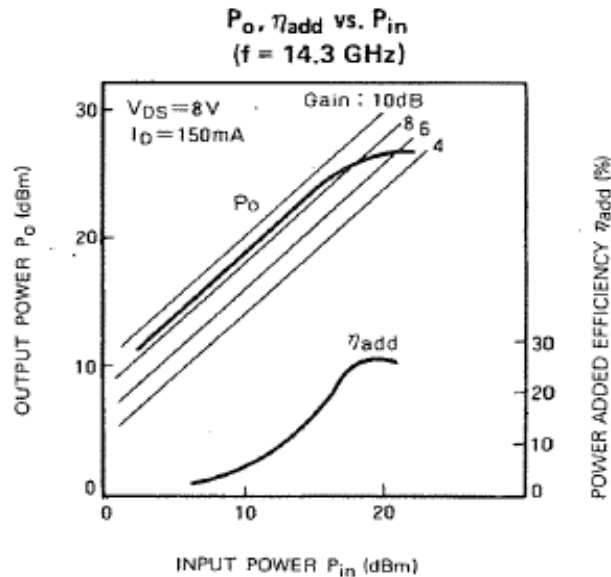
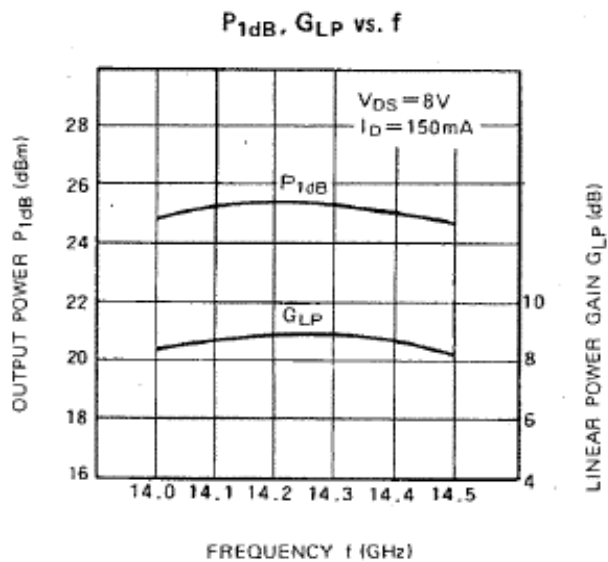
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## MGFK25V4045 TYPICAL CHARACTERISTICS



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